

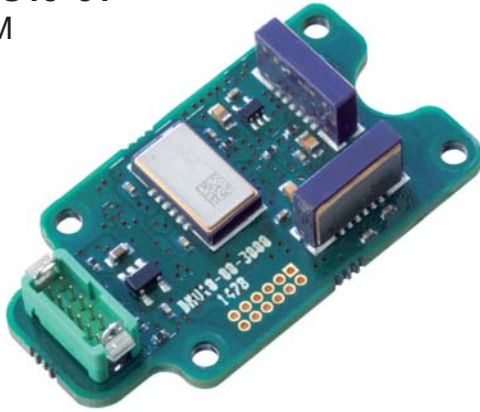
DMU10 Technical Datasheet

Six Degrees of Freedom Precision
MEMS Inertial Measurement Unit

**SILICON
SENSING**®

www.siliconsensing.com

DMU10-01 OEM



DMU10-02 Module



Features

- High performance six degrees of freedom (6-DOF) MEMS IMU
- 7 sensor inputs
 - Angular rate (x3)
 - Linear acceleration (x3)
 - Temperature
- Dynamic Range $\pm 300^\circ/\text{s}$ and $\pm 10\text{g}$
- Bias instability $< 10^\circ/\text{hr}$ and 0.05mg
- Random Walk $< 0.7^\circ/\sqrt{\text{hr}}$ and 0.1m/s
- Small (45 x 26 x 16mm)
- User programmable bandwidth
- 3.2 to 5.25V Supply
- Wide operating temperature range -40°C to $+85^\circ\text{C}$
- RS-422 Interface
- Optional Configurations:
 - Uncalibrated and thermally calibrated
 - OEM and Module
- RoHS compliant

Applications

- Machine control
- Antenna and Platform Stabilisation
- Precision Agriculture
- Autonomous Vehicles and ROVs
- Attitude Measurement Systems
- Personal Navigation
- GPS Aiding

1 General Description

DMU10 is a 6-DOF Precision MEMS Inertial Measurement Unit from Silicon Sensing Systems. It provides three axes of angular rate and linear acceleration, and temperature. The output message includes message counter, built-in test results, delta theta and delta velocity information. Data is output on an industry standard RS422 interface for ease of integration.

DMU10 is engineered using Silicon Sensing's own unique MEMS VSG5 ring gyroscope and capacitive accelerometer technologies to provide benchmark performance, size and affordability. It contains three 5th generation piezoelectric (PZT) gyroscopes and six accelerometers. Outputs from dual accelerometers per axis are averaged to improve precision and reduce uncorrelated noise.

Available uncalibrated or calibrated over the full operating temperature range. DMU10 is supplied either as an OEM or a Module.

Full Evaluation Kit available (see Section 8 for details).

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MEMS Inertial Measurement Unit

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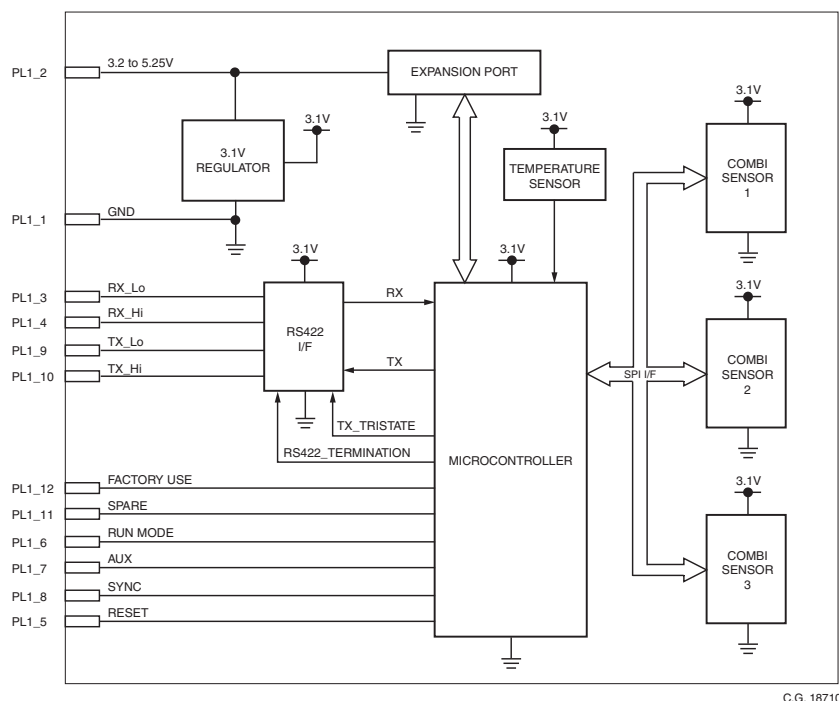
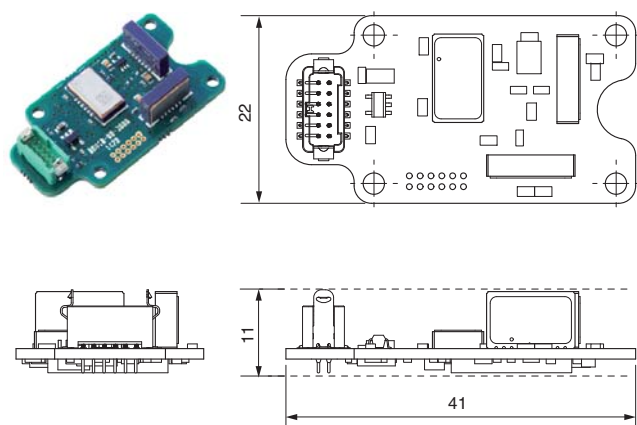
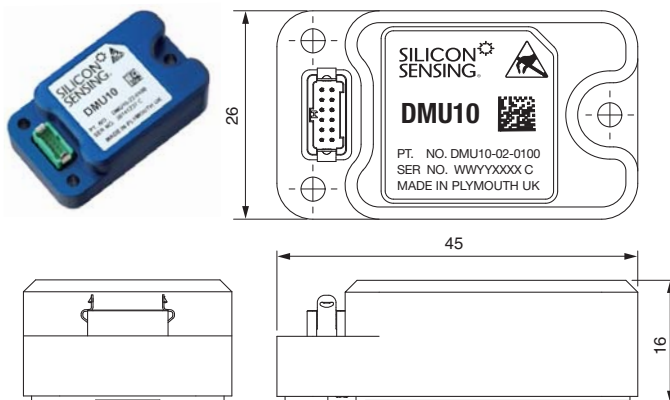


Figure 1.1 DMU10 Functional Block Diagram



All dimensions in millimetres.

**Figure 1.2 DMU10 (OEM) Unit
Overall Dimensions**



All dimensions in millimetres.

**Figure 1.3 DMU10 (Module) Unit
Overall Dimensions**

DMU10 Technical Datasheet

Six Degrees of Freedom Precision
MEMS Inertial Measurement Unit



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2 Ordering Information

Calibration: UN = Uncalibrated, OT = Over Temperature Calibration

Item	Description	Overall Dimensions	Calibration	Part Number
		mm		
 DMU10 OEM Unit	Bare PCB with four mounting holes	41 x 22 x 10.6	UN	DMU10-01-0100
			OT	DMU10-21-0100
 DMU10 Module Unit	A two-part, anodised aluminium, non-hermetic housing. Three mounting lugs.	45 x 26 x 16	UN	DMU10-02-0100
			OT	DMU10-22-0100
 DMU10 OEM Evaluation Kit	Customer evaluation kit comprising a DMU10-21-0100, RS422 to USB Connector, USB Driver and Data Logging Software, Cables and Connectors, Instruction Manual.	Not Applicable	OT	DMU10-21-0500

3 Performance

Calibration: UN = Uncalibrated, OT = Over Temperature Calibration

Parameter	CAL	Minimum	Typical	Maximum	Notes
Angular Rate (Roll, Pitch, Yaw)					
Dynamic Range (°/s)	All	< -300	–	> +300	Clamped at ±305°/s during over-range
Scale Factor Error (%)	UN	-3.00	±1.50	+3.00	–
	OT	-0.25	±0.10	+0.25	–
Scale Factor Non-Linearity Error (%)	UN	-0.125	±0.05	+0.125	–
	OT	-0.067	±0.033	+0.067	–
Bias (°/s)	UN	-3.30	±1.65	+3.30	Over operating temperature range
	OT	-0.50	±0.25	+0.50	
Bias drift with time (°/s)	UN	-0.20	±0.10	+0.20	At constant temperature
	OT	-0.05	±0.025	+0.05	
Bias Instability (°/h)	All	–	< 15.00	–	As measured using the Allan Variance method.
Angle Random Walk (°/√h)	All	–	< 0.40	–	
Bias Repeatability (°/h)	UN	-3600	±1800	+3600	$\text{Bias Repeatability} = \sqrt{(\text{BiasWarmup})^2 + (\text{BiasSto})^2 + (\text{BiasSaging})^2 + (\text{BiasTemperature})^2}$
	OT	-300	±150	+300	
Gyro Cross Coupling (%)	UN	-6.00	±2.00	+6.00	Over operating temperature range
	OT	-0.7	±0.35	+0.7	
Gyro Bandwidth (Hz)	All	< 10	85	> 150	-3dB point User programmable
Noise (°/s rms)	All	–	0.10	0.15	Wide band noise at 100Hz bandwidth
VRE (°/s rms / g)	All	-0.006	±0.003	+0.006	3.3g rms stimulus 20Hz to 2,000Hz

3 Performance Continued

Parameter	CAL	Minimum	Typical	Maximum	Notes
Linear Acceleration (X, Y, Z)					
Dynamic Range (g)	All	< -10	–	> +10	Clamped at ±10.01g during over-range
Scale Factor Error (%)	UN	-3.00	±1.00	+3.00	–
	OT	-0.25	±0.10	+0.25	–
Scale Factor Non-Linearity Error (%)	UN	-1.00	±0.50	+1.00	Maximum error from best straight line over ±8g
	OT	-1.00	±0.50	+1.00	
Bias (mg)	UN	-150.00	±50.00	+150.00	Over operating temperature range
	OT	-10.00	±2.50	+10.00	
Bias drift with time (mg)	UN	-20.00	±10.00	+20.00	At constant temperature
	OT	-2.00	±1.00	+2.00	
Bias Instability (mg)	All	–	< 0.05	–	As measured using the Allan Variance method.
Angle Random Walk (m/s/√h)	All	–	< 0.05	–	
Bias Repeatability (mg)	UN	-30	±15	+30	$\text{Bias Repeatability} = \sqrt{(\text{BiasWarmup})^2 + (\text{BiasStato})^2 + (\text{BiasSageing})^2 + (\text{BiasTemperature})^2}$
	OT	-2	±1	+2	
Acc Cross Coupling (%)	UN	-6.00	±3.00	+6.00	Over operating temperature range
	OT	-0.70	±0.35	+0.70	
Acc Bandwidth (Hz)	All	< 10	90	> 150	-3dB point User programmable
Noise (mg rms)	All	–	1.00	1.50	Wide band noise at 100Hz bandwidth
Temperature Output					
Range (°C)	All	< -45	–	> 100	Exceeds operational temperature range
Accuracy (°C)	All	–	±3	–	In the operational temperature range

4 Environment, Power and Physical

Parameter	Minimum	Typical	Maximum	Notes
Environment				
Operating Temperature Range (°C)	-40	–	+85	Full specification
Storage Temperature Range (°C)	-55	–	+100	–
Operational Shock (g)	–	–	95	6ms, half sinewave
Non-Operational Shock (g)	–	–	500	0.1ms, half sinewave
Operational Random Vibration (g rms)	–	–	3.3	20Hz to 2KHz
Non-Operational Random Vibration (g rms)	–	–	10	20Hz to 2KHz
Humidity (% rh)	–	–	85	Non-condensing
Interface				
Communication Protocol (Standard)	–	RS-422	–	Full duplex communication
Data Rate (Hz)	–	200 (Default)	–	User programmable * future feature
Baud Rate (BPS)	–	460, 800 (Default)	–	User programmable * future feature
Startup Time (s)	–	< 0.5	–	–
Current (mA)	–	85	95	With 120 Ω RS422 termination resistor
Voltage (V)	+3.2	+5	+5.25	–
Physical (OEM)				
Size (mm)	–	41 x 22 x 10.6	–	–
Mass (grams)	–	6	–	–
Physical (Module)				
Size (mm)	–	45 x 26 x 16	–	–
Mass (grams)	–	24	–	–

5 Typical Performance Characteristics

This section shows the typical performance of DMU10 (Uncalibrated and Calibrated).

5.1 Performance Characteristics (Uncalibrated)

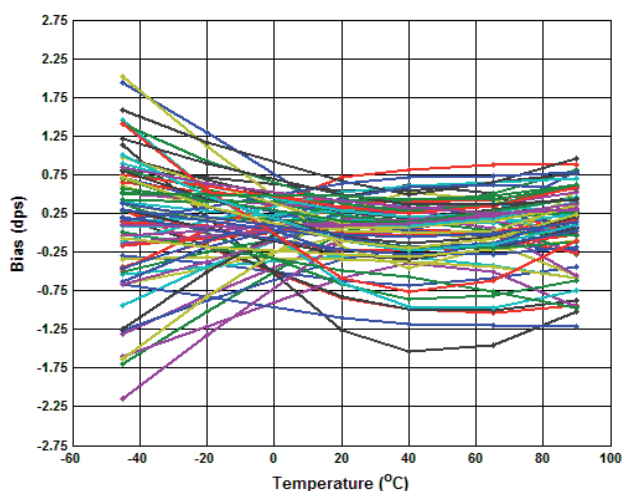


Figure 5.1 Gyroscope Bias

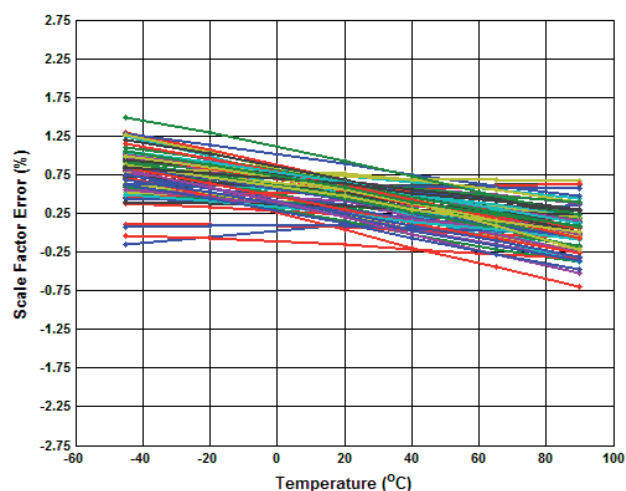


Figure 5.2 Gyroscope Scale Factor Error

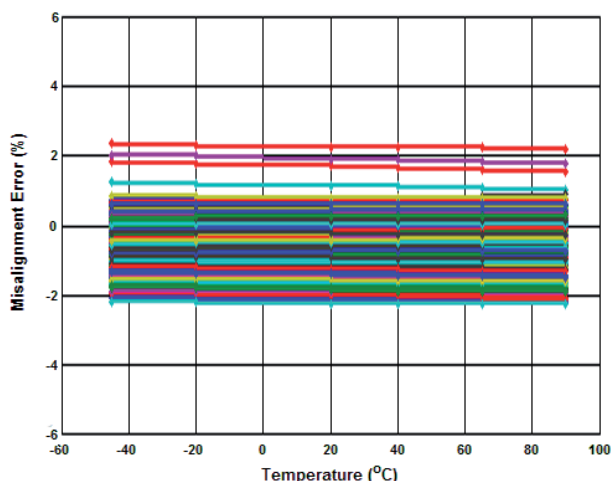


Figure 5.3 Gyroscope Cross Coupling

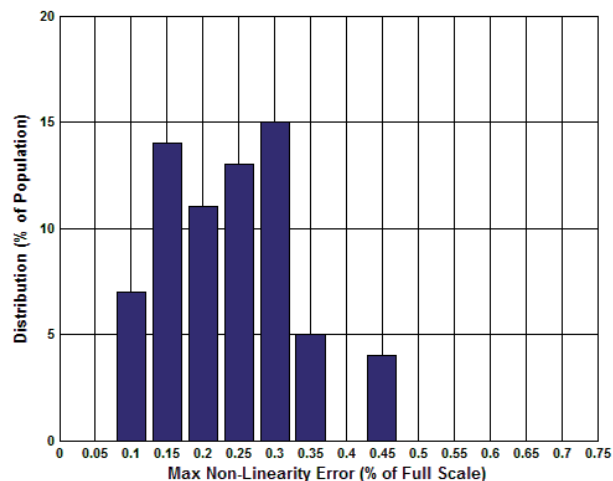


Figure 5.4 Gyroscope Non-Linearity
Distribution

Typical Performance Characteristics (Uncalibrated)

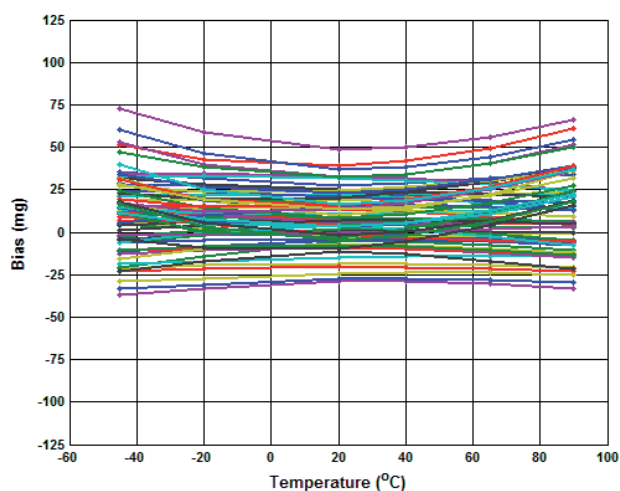


Figure 5.5 Accelerometer Bias

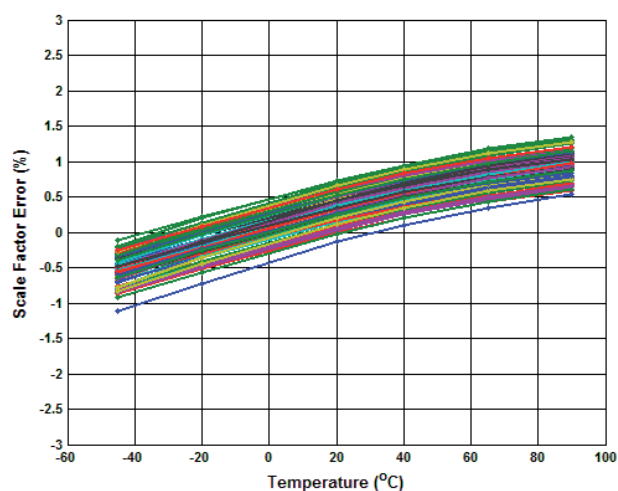


Figure 5.6 Accelerometer Scale Factor Error

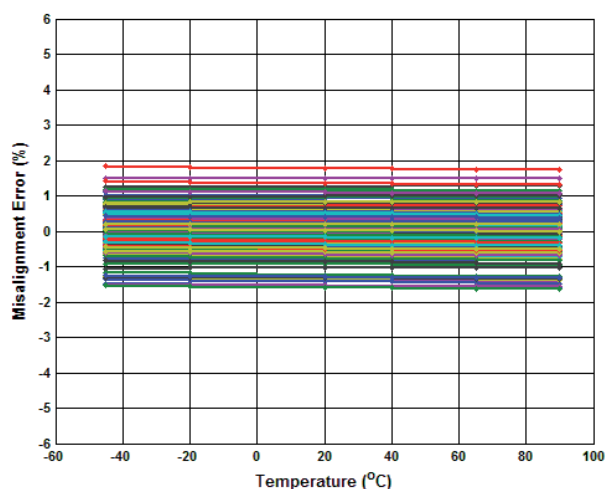


Figure 5.7 Accelerometer Cross Coupling

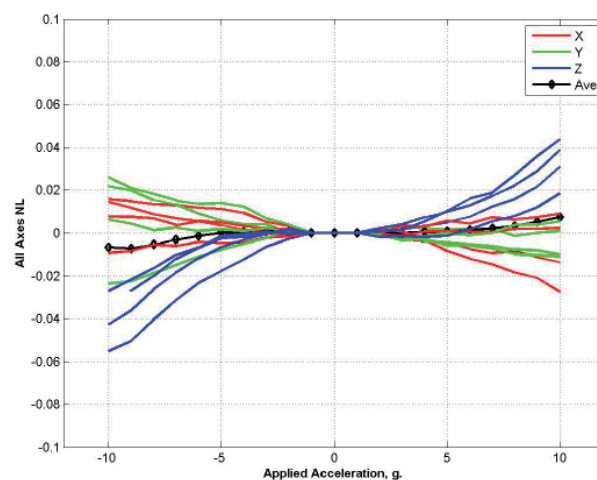


Figure 5.8 Accelerometer Non-Linearity Error

5.2 Typical Performance Characteristics (Calibrated)

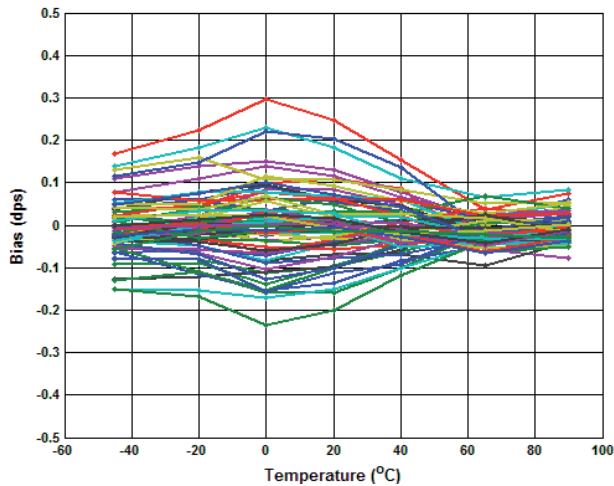


Figure 5.9 Gyroscope Bias

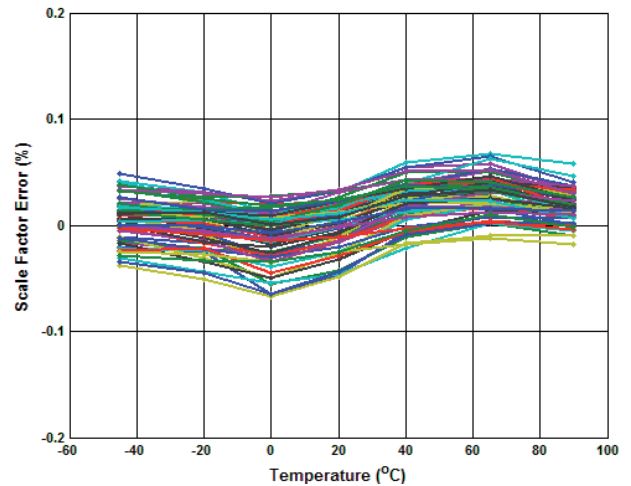


Figure 5.10 Gyroscope Scale Factor Error

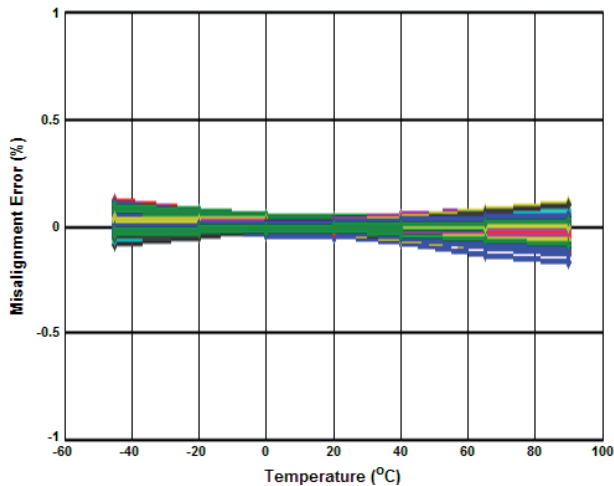


Figure 5.11 Gyroscope Cross Coupling

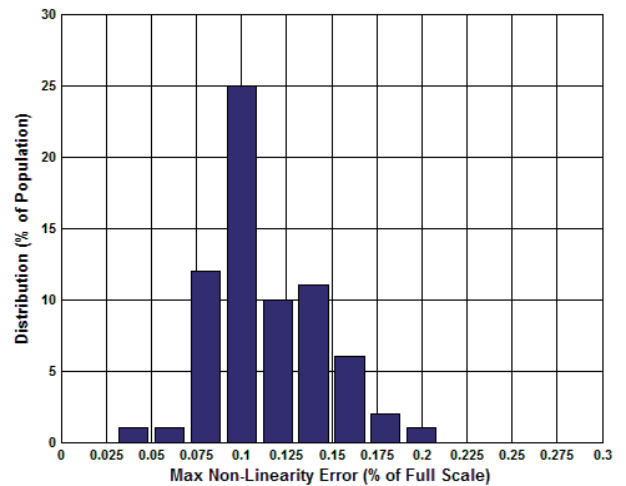


Figure 5.12 Gyroscope Non-Linearity
Distribution

Typical Performance Characteristics (Calibrated)

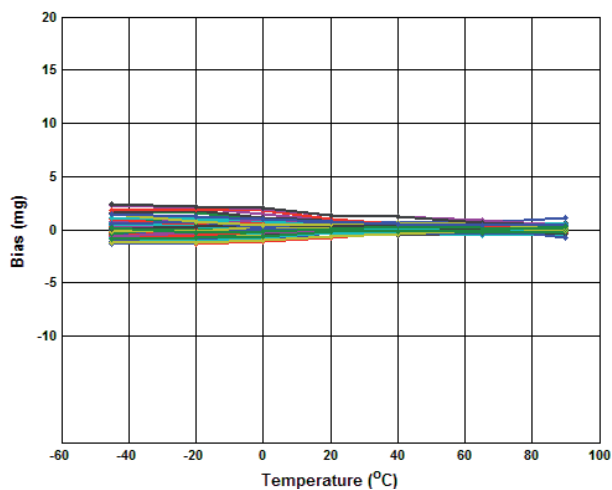


Figure 5.13 Accelerometer Bias

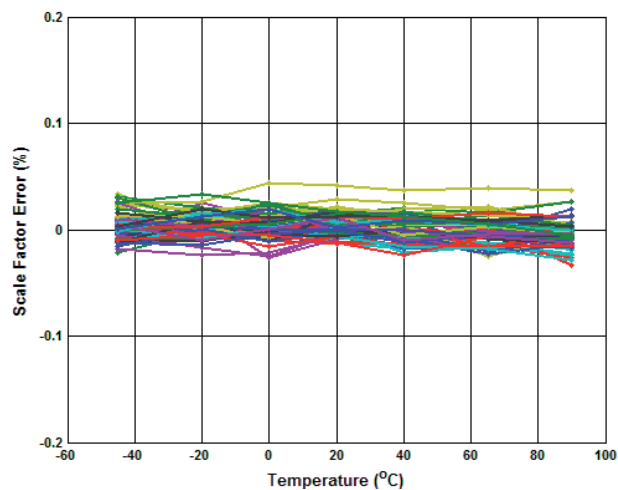


Figure 5.14 Accelerometer Scale Factor Error

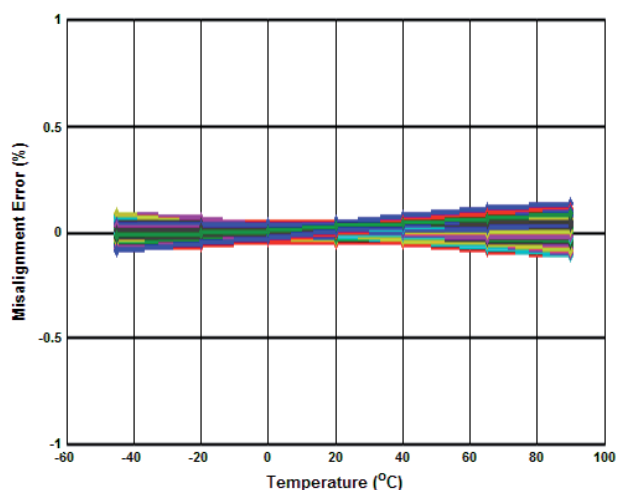


Figure 5.15 Accelerometer Cross Coupling

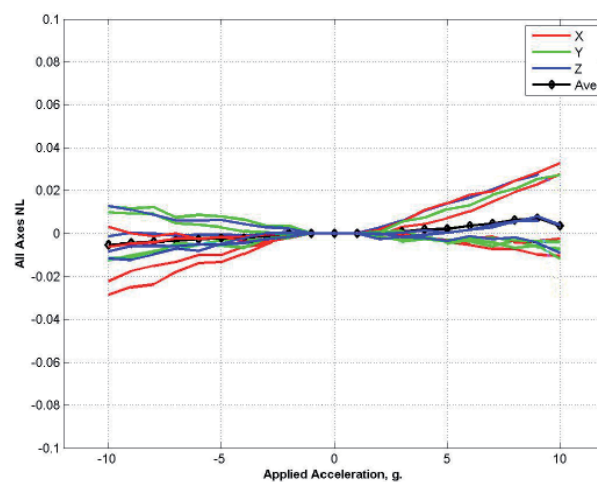


Figure 5.16 Accelerometer Non-Linearity Error

5.3 Typical Performance Characteristics (Uncalibrated and Calibrated)

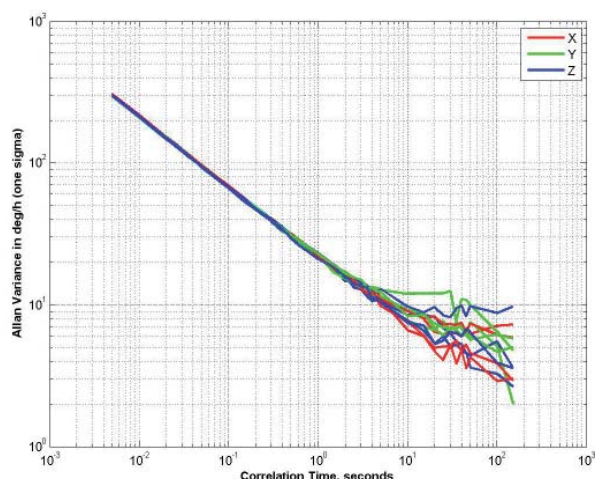


Figure 5.17 Gyroscope Allan Variance

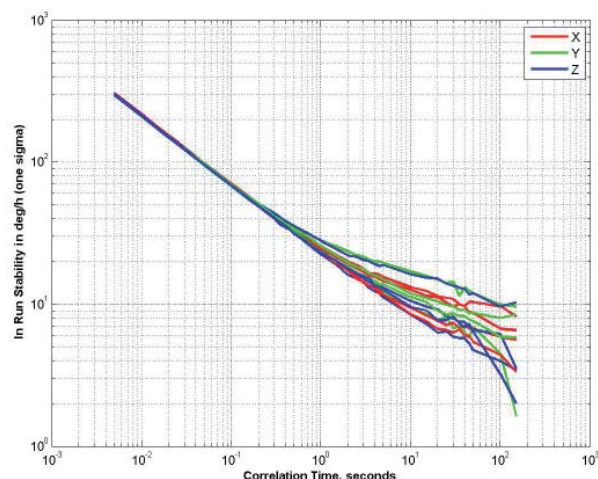


Figure 5.18 Gyroscope Stability

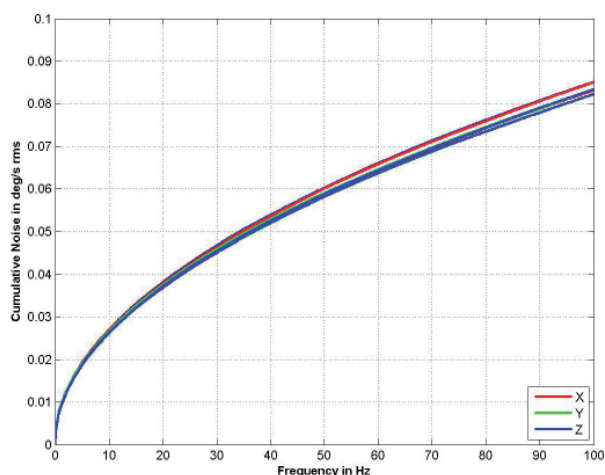


Figure 5.19 Gyroscope Cumulative Noise

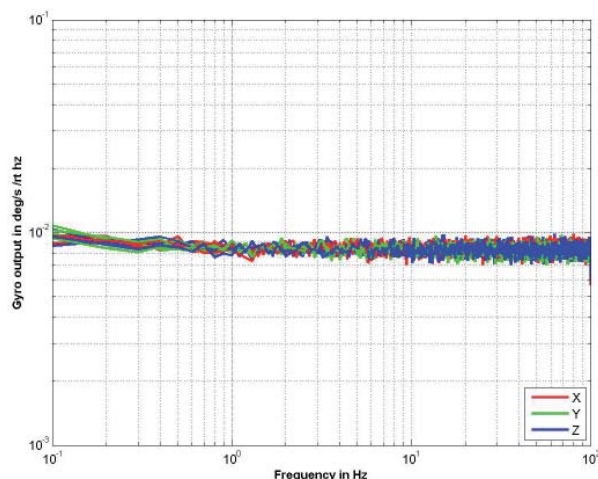


Figure 5.20 Gyroscope Spectral Noise

Typical Performance Characteristics (Uncalibrated and Calibrated)

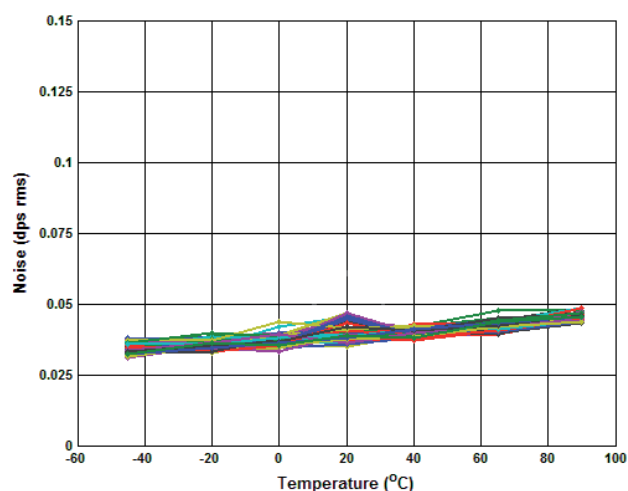


Figure 5.21 Gyroscope Noise over Temperature

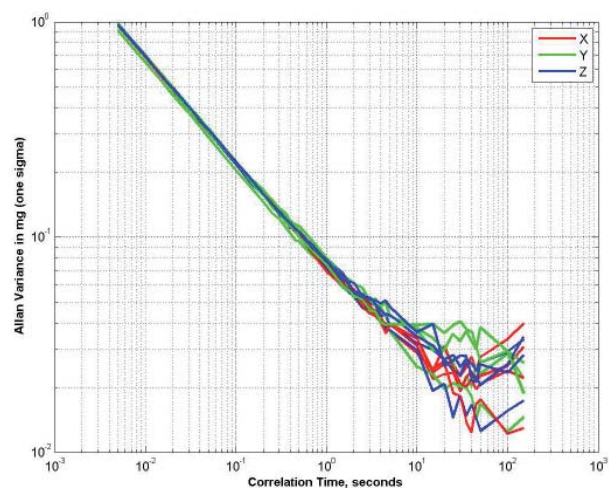


Figure 5.22 Accelerometer Allan Variance

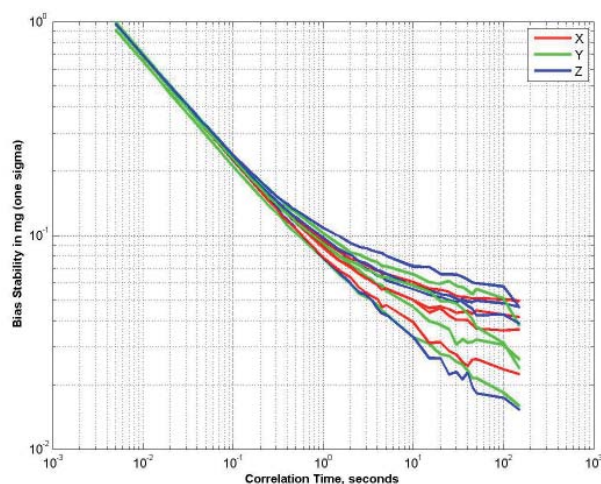


Figure 5.23 Accelerometer Stability

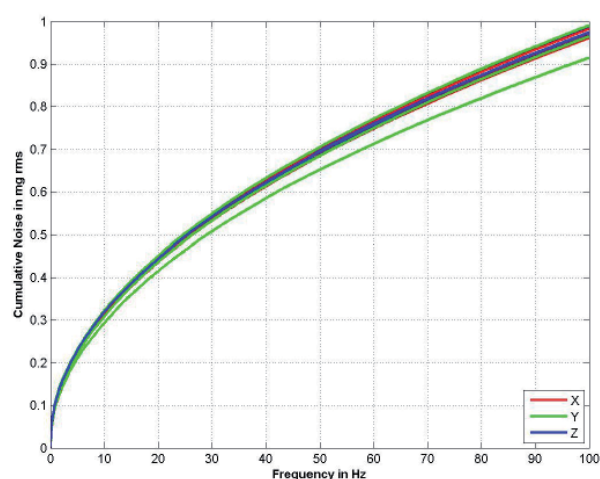


Figure 5.24 Accelerometer Cumulative Noise

Typical Performance Characteristics (Uncalibrated and Calibrated)

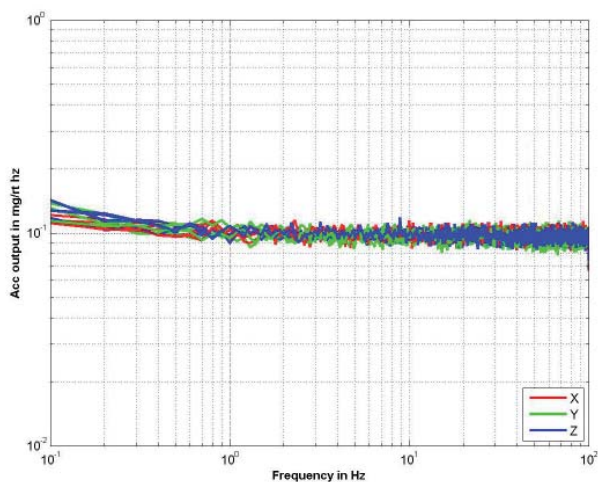


Figure 5.25 Accelerometer Spectral Noise

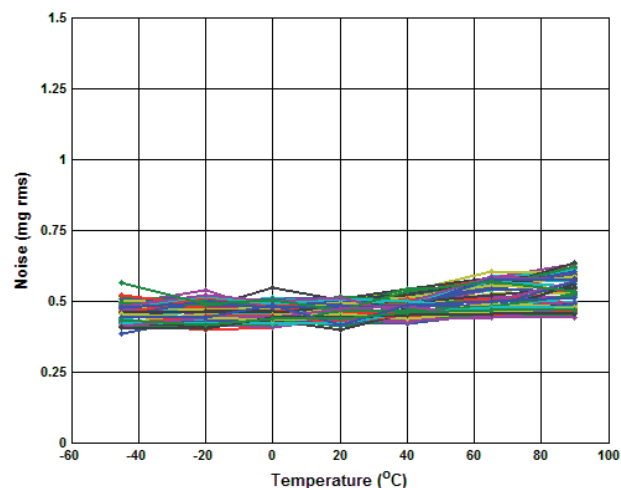


Figure 5.26 Accelerometer Noise over Temperature

6 Glossary of Terms

ADC	Analogue to Digital Converter
ARW	Angle Random Walk
AWG	American Wire Gauge
BPS	Bits Per Second (or Baud Rate)
BW	Bandwidth
C	Celsius or Centigrade
DAC	Digital to Analogue Converter
DPH	Degrees Per Hour
DPS	Degrees Per Second
DRIE	Deep Reactive Ion Etch
EMC	Electro-Magnetic Compatibility
ESD	Electro-Static Damage
F	Farads
h	Hour
HBM	Human Body Model
Hz	Hertz, Cycles Per Second
K	Kilo
MDS	Material Datasheet
MEMS	Micro-Electro Mechanical Systems
mV	Mili-Volts
NEC	Not Electrically Connected
NL	Scale Factor Non-Linearity
OEM	Original Equipment Manufacturer
OT	Over Temperature
PD	Primary Drive
PP	Primary Pick-Off
RC	Resistor and Capacitor filter
RT	Room Temperature
s	Seconds
SF	Scale Factor
SMT	Surface Mount Technology
SOG	Silicon On Glass
SD	Secondary Drive
SP	Secondary Pick-Off
T.B.A.	To Be Advised
T.B.D.	To Be Determined
V	Volts

7 Interface

Physical and electrical inter-connect and RS422 message information

7.1 Electrical Interface

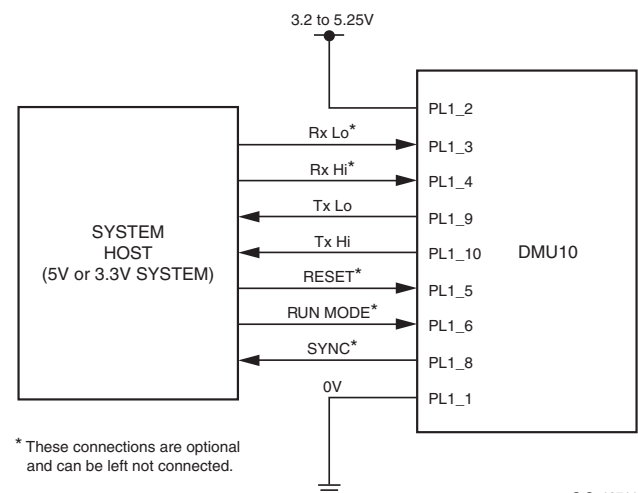
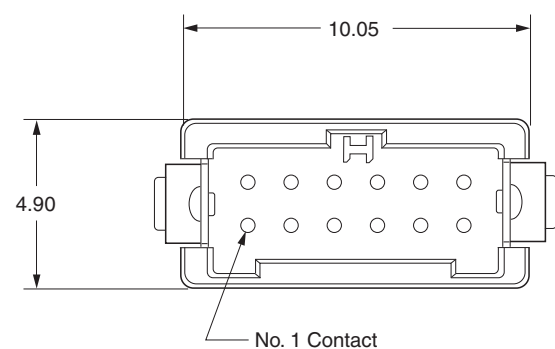


Figure 7.1 Required Connections for RS422 Communications with DMU10

7.2 Physical Interface



Part No: HARWIN G125-MV11205L1

C.G. 18720

Figure 7.2 Male Connector DMU10

7.3 Connector Specification

The physical connector for the DMU10 is from the 'Gecko' family of connectors, produced by Harwin.

The part number for the board connector is G125-MV11205L1. The female mating connector used to interface with this connector is part number G125-204 12 96 L0 (with crimps G125-0010003 for 26 AWG wires or G125-0010005 for 28 AWG wires).

7.4 Pin Information

Pin	Label	Signal	In/Out
1	GND	Ground connected of the DMU10	I
2	+5V	Input voltage to the DMU10. Can be between 3.2V and 5.25V	I
3	Rx Lo	The negative receive connection required for the RS422 communication	I
4	Rx Hi	The positive receive connection required for the RS422 communication	I
5	Reset	Microprocessor reset. Pin is pulled low to reset the device. Suggested implementation using TTL logic	I
6	Run Mode	Device Enable/Disable. Pin is pulled high or not connected to enable the device. Pin is pulled low to disable the device. Suggested implementation using TTL logic	I
7	Aux	Analogue input channel which integrates a signal into the output message of the DMU10. This functionality can be used to allow the user to synchronise with a known input clock	I
8	Sync	Output signal that can be used by an external system to synchronise with DMU10	O
9	Tx Lo	The negative transmit connection required for the RS422 communication	O
10	TX Hi	The positive transmit connection required for the RS422 Communication	O
11	Spare	Not electrically connected	N/A
12	Factory Use	Used by SSSL for programming purposes and should not be interfaced with	N/A

Table 7.1 Pin Information

7.5 Communications with DMU10

The Run Mode pin on the connector is used to control the output from the DMU10. The "Free Run" or "Enabled" mode is active when the Pin is floating (not connected), and the output will be enabled.

The DMU10 output is disabled when the "Run Mode" Pin is pulled low.

7.6 Operational Message Output

The Output Message is output on a RS422 Serial output at 460,800 baud using a non-return to zero protocol. Each byte contains a start bit (logic 0), 8 data bits and 2 stop bits (logic 1). Data is output in big endian format by default.

Data is output at a rate of 200 messages per second.

Each message contains 33 words (66 bytes) as described in Table 7.2. The message is transmitted if the "Run Mode" Pin is Low.

If the "Run Mode" Pin changes to a High (Disable output), while the message is being transmitted, the message is completed before the output is disabled.

7.7 Sensor Sampling and Synchronisation

The Inertial Sensors within DMU10 are all sampled at 1,000Hz. The 'Sync Pulse' on the connector is set HIGH at the start of the sampling and returned to LOW when the last Inertial Sensor is sampled. Pulses are therefore seen on the connector at 1,000Hz.

The Inertial Sensor measurements are then filtered with a 2nd order low pass filter, also running at 1000Hz. The factory default setting for this filter has a corner frequency of > 85Hz.

The internal sequence for DMU10 is:

- Cycle 1: Sample Sensors, 2nd order Filter
- Cycle 2: Sample Sensors, 2nd order Filter, Calculate Sensor Compensation
- Cycle 3: Sample Sensors, 2nd order Filter, Apply Sensor Compensation
- Cycle 4: Sample Sensors, 2nd order Filter, Calculate Delta Theta and Vels
- Cycle 5: Sample Sensors, 2nd order Filter, Transmit Message

The message is transmitted after the 'Sync Pulse' associated with Cycle 5 has returned LOW. The inertial data included in the message is generated when the 'Sync Pulse' associated with Cycle 3 was HIGH. This enables the external equipment to synchronise with the time when the Inertial Data was valid.

7.8 Operational Message Definitions

The data output message has the content and sequence as shown in the table below:

Item	Word	Data Item	Value / Unit
0	0	Header	16 Bit, 0x55AA
1	1	Message Count	16 Bit, 0 to 65535 decimal
2	2-3	Axis X Rate	32 Bit Single Precision FP, (°/s)
3	4-5	Axis X Acceleration	32 Bit Single Precision FP, (g)
4	6-7	Axis Y Rate	32 Bit Single Precision FP, (°/s)
5	8-9	Axis Y Acceleration	32 Bit Single Precision FP, (g)
6	10-11	Axis Z Rate	32 Bit Single Precision FP, (°/s)
7	12-13	Axis Z Acceleration	32 Bit Single Precision FP, (g)
8	14-15	Aux Input Voltage	32 Bit Single Precision FP, (volts)
9	16-17	Average IMU Temperature	32 Bit Single Precision FP, (°C)
10	18-19	Axis X Delta Theta	32 Bit Single Precision FP, (°)
11	20-21	Axis X Delta Vel	32 Bit Single Precision FP, (m/s)
12	22-23	Axis Y Delta Theta	32 Bit Single Precision FP, (°)
13	24-25	Axis Y Delta Vel	32 Bit Single Precision FP, (m/s)
14	26-27	Axis Z Delta Theta	32 Bit Single Precision FP, (°)
15	28-29	Aux Z Delta Vel	32 Bit Single Precision FP, (m/s)
16	30	System Startup BIT Flags	16 Bit decimal value
17	31	System Operation BIT Flags	16 Bit decimal value
18	32	Error Operation BIT Flags	16 Bit decimal value
19	33	Checksum	16 Bit 2's Complement of the 16 Bit Sum of the Previous 0-18 data items

Table 7.2 Operational Message Data Output Definitions

7.9 System BIT Flags

7.9.1 System Startup BIT Flags

These flags indicate errors detected during DMU10 Initialisation. Once set, these flags will not be cleared for the whole of the power cycle.

BIT No.	System Startup BIT Flags
D00	Code_Checksum_Fail Set if the DMU10 code checksum does not match. If this flag is set, correct operation of the DMU10 cannot be guaranteed.
D01	NVM_Coefficient_Checksum_Fail Set if the DMU10 NVM coefficient checksum does not match. If this flag is set, correct operation of the DMU10 cannot be guaranteed.
D02	Orion_Startup_Error This flag will be set if there were any Orion Startup Flags set in any of the three 32 BIT Orion BIT flag arrays. The output items affected by this failure will be marked in the Item Error Indication table.
D03	Internal_Processor_Error Set if there was an error accessing hardware internal to the microprocessor.
D04	Invalid_NVM_Coefficient Set if an NVM coefficient value is invalid. If this affects an operational output item, the corresponding item will be marked in the Item Error Indication table and this should help to identify which coefficient is invalid.
D05	Spare
D06	Spare
D07	Spare
D08	Spare
D09	Spare
D010	Spare
D011	Spare
D012	Spare
D013	Spare
D014	Spare
D015	Spare

Table 7.3 System Startup BIT Flags

7.9.2 System Operation BIT Flags

These flags indicate errors detected during DMU10 operation. These flags are set per DMU10 output message and so may not appear in every returned message (because the fault may clear or be intermittent).

BIT No.	System Operation BIT Flags
D00	Voltage_Regulator_Range_Error Regulator Voltage BIT Function.
D01	Scheduler_Slot_Period_Extended This flag will be set if the DMU10 software scheduler could not complete its allocated tasks within the required slot time. If this happens, the DMU10 will widen it's scheduler slot time. This will normally be caused by a hardware fault that caused a timeout. When this flag is set, the DMU10 will output data at a decreased rate.
D02	Output_Message_Missed This flag will be set if the previous output message was missed. This will occur if the DMU10 was unable to output a serial port message because the previous message was still being sent. This will normally be caused by incompatible Message or Baud Rate selection.
D03	Internal_Processor_Error This flag will be set if the software timed out while accessing hardware internal to the microprocessor (A/D, SPI). The output items affected by this failure will be marked in the Item Error Indication table.
D04	Orion_Operation_Error This flag will be set if there are any Orion Operation Flags set in any of the three 32 BIT Orion BIT flag arrays. The output items affected by this failure will be marked in the Error Indication table.
D05	Output_Value_Out_Of_Range Set when an output value has been clamped because it is out of range. The output items affected by this failure will be marked in the Error Indication table. Max Rate = $\pm 305^\circ/\text{s}$ Max Acceleration = $\pm 10.01\text{g}$
D06	Plausibility_Error Set when the system has determined that a sampled sensor value is implausible. The output items affected by this failure will be marked in the Error Indication table. This currently only applies to accelerometer sensors which have corresponding sensors in the same sense axis.
D07	Spare
D08	Spare
D09	Spare
D010	Spare

BIT No.	System Operation BIT Flags
D011	Spare
D012	Spare
D013	Spare
D014	Spare
D015	Spare

Table 7.4 System Operation BIT Flags

7.9.3 System Error Indication BIT Flags

These flags indicate which message items have faults associated with them.

BIT No.	System Error Indication BIT Flags
D00	Message Item 01 Error (X axis Rate for standard message format).
D01	Message Item 02 Error (X axis acceleration for standard message format).
D02	Message Item 03 Error (Y axis Rate for standard message format).
D03	Message Item 04 Error (Y axis acceleration for standard message format).
D04	Message Item 05 Error (Z axis Rate for standard message format).
D05	Message Item 06 Error (Auxillary input for standard message format).
D06	Message Item 07 Error (Temperature for standard message format).
D07	Message Item 08 Error (X delta theta for standard message format).
D08	Message Item 09 Error (X delta velocity for standard message format).
D09	Message Item 10 Error (Y delta theta for standard message format).
D010	Message Item 11 Error (Y delta velocity for standard message format).
D011	Message Item 12 Error (Z delta theta for standard message format).
D012	Message Item 13 Error (Z delta velocity for standard message format).
D013	Message Item 14 Error.
D014	Message Item 15 Error.
D015	Message Item 16 Error.

Table 7.5 System Error Indication BIT Flags

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8 Design Tools and Resources Available

Item	Description of Resource	Part Number	Order/Download
	DMU10 Brochure: A one page sales brochure describing the key features of the DMU10 Inertial Measurement Unit.	DMU10-00-0100-131	Download (www.siliconsensing.com)
	DMU10 Datasheet: Full technical information on all DMU10 Dynamic Measurement Unit part number options. Specification and other essential information for assembling and interfacing to DMU10 Inertial Measurement Unit, and getting the most out of it.	DMU10-00-0100-132	Download (www.siliconsensing.com)
	DMU10 Evaluation Kit: DMU10 delivered with an RS422 to USB interface, plug-and-play real time display and logging software and two interface cabling solutions DMU10-21-0100 unit included.	DMU10-21-0500	Order (www.siliconsensing.com)
	DMU10 Presentation: A useful presentation describing the features, construction, principles of operation and applications for the DMU10 Inertial Measurement Unit.	—	Download (www.siliconsensing.com)
	Solid Model CAD files for DMU10 Inertial Measurement Unit: Available in .STP and .IGS file format.	DMU10-01-0100-408	Download (www.siliconsensing.com)
		DMU10-02-0100-408	
	Interface: Off-the-peg pseudo code and a simple flowchart with message handling instructions for use as a customer aid to developing their own interface directly to a DMU10 Inertial Measurement Unit via the RS422 interface.	—	Download (www.siliconsensing.com)
	Questions and Answers: Some useful questions asked by customers and how we've answered them. This is an informal (uncontrolled) document intended purely as additional information.	—	Download (www.siliconsensing.com)
	RoHS compliance statement for DMU10: DMU10 is fully compliant with RoHS. For details of the materials used in the manufacture please refer to the MDS Report.	—	Download (www.siliconsensing.com)

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8.1 DMU10 Evaluation Kit

The DMU10 Evaluation Kit enables the output data from the DMU10 to be viewed and logged for testing and evaluation purposes.



Figure 8.1 DMU10 Evaluation Kit

8.1.1 DMU10 Evaluation Kit Contents

The DMU10 Evaluation Kit (part number DMU10-21-0500) contains the following:

DMU10 IMU (part number DMU10-21-0100).

- MEV RS485i to USB converter.
- CD containing the MEV drivers.
- USB memory stick containing the data logging software.
- Interface cables.
- User manual.

8.1.2 System Requirements

The DMU10 Evaluation Kit requires a PC with a USB port. The requirements for the PC are as follows:

- Microsoft® Windows® XP (SP3 or greater), Vista®, Windows 7 or Windows 8 Operating Systems. The software has not been tested on any other Operating System and therefore correct functionality cannot be guaranteed.
- Minimum of 500Mb of RAM.
- 500Mb of free hard drive space plus space for logged data (typical data rate $\approx$ 50kbit/s).
- High power or self-powered USB 2.0 Port.

9 Part Markings

DMU10 is supplied with an adhesive label attached. The label displays readable DMU10 part and part identification numbers.

The part identification number is a numeric code; WWYYXXXX C where:

- WW = Manufacturing week number
- YY = Manufacturing year number
- XXXX = Serial number
- C = Revision

A 4x4 data matrix barcode containing the part identification number is also displayed on the label.

10 Installation Details

Figures 10.1 and 10.2 show the installation drawing for the DMU10, the OEM and Module versions respectively.

The DMU10 (OEM) is supplied as a PCBA. It is recommended that the PCBA is mounted on spacers or pillars using the four mounting holes provided. The holes are clearance holes for use with M2.0 screws. During calibration, alignment is achieved using external reference dowels on two sides of the PCBA. These two sides therefore form the datum for alignment purposes.

The DMU10 (Module) is designed for 3 point mounting using M2.5 screws. During calibration alignment is achieved using two external reference dowel holes on the base of the DMU10. The dowel holes are designed to be used with two Ø2mm (in accordance with BS EN ISO 8734 or BS EN ISO 2338) dowel pins provided by the host.

The DMU10 mounting screw torque settings will be dependent on the host application; it will for example vary depending on the specification of the screw, the material of the host structure and whether a locking compound is used. When securing a DMU10 OEM unit to the host system using steel M2 screws and a thread locking compound the suggested torque setting is 0.1Nm for securing to an aluminium host structure. When securing a DMU10 Module unit to the host system using steel M2.5 screws and a thread locking compound the suggested torque setting is 0.2Nm for securing to an aluminium host structure. This information is provided for guidance purposes only, the actual torque settings are the responsibility of the host system designer.

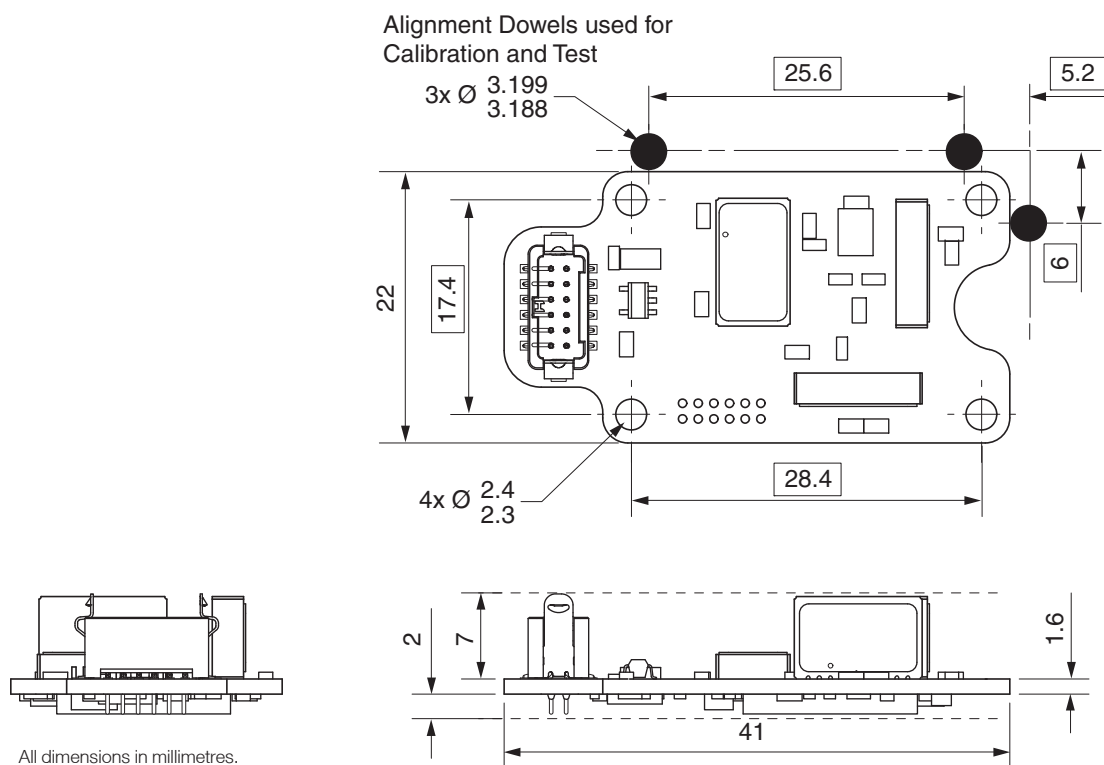


Figure 10.1 DMU10 (OEM) Installation Drawing

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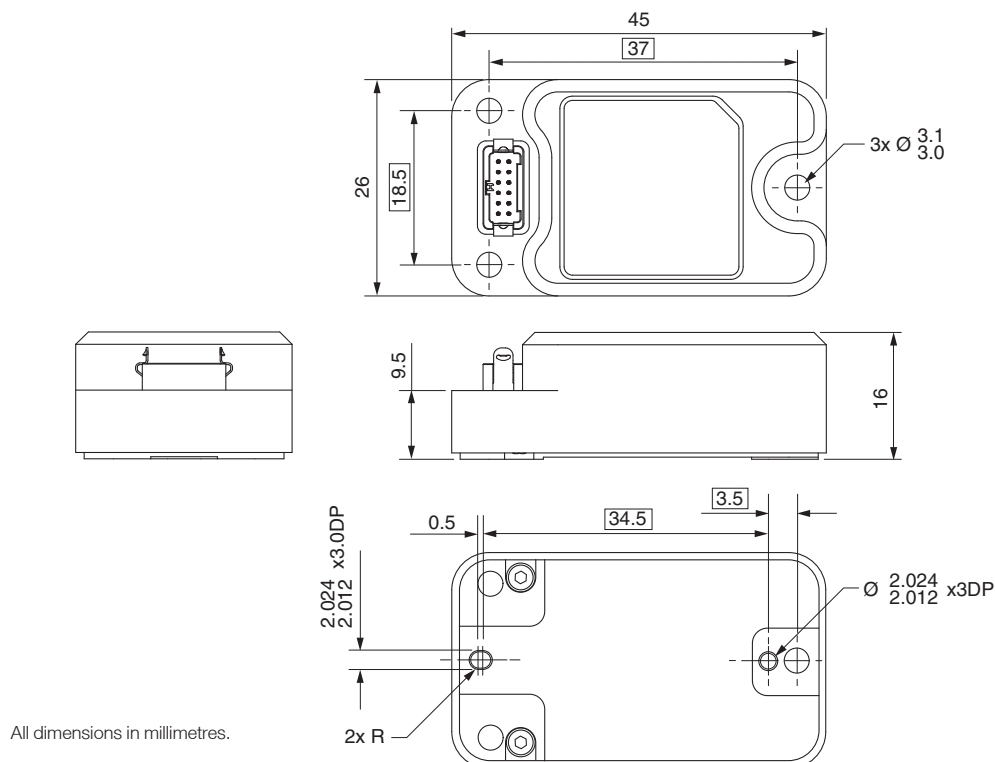


Figure 10.2 DMU10 (Module) Installation Drawing

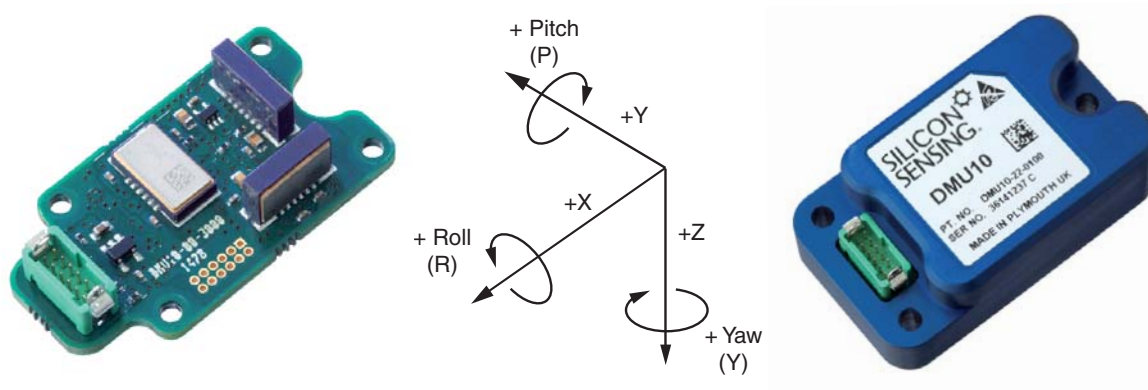


Figure 10.3 Axis Definitions

11 DMU10 MEMS Sensor Internal Construction and Theory of Operation

Construction

The DMU10 uses three MEMS rate and acceleration Combi-Sensors providing three gyroscopes and six accelerometers.

Each Combi-Sensor comprises six main components; Silicon MEMS Single-Axis Angular Rate Sensor, Silicon On Glass (SOG) Dual-Axis MEMS Accelerometer, Silicon Pedestal, ASIC Package Base and Lid. The MEMS Sensors, ASIC and Pedestal are housed in a hermetically sealed package cavity with a nitrogen back-filled partial vacuum, this has particular advantages over sensors supplied in plastic packages which have Moisture Sensitivity Level limitations.

An exploded drawing of a Combi-Sensor showing the main components is given in Figure 11.1 below.

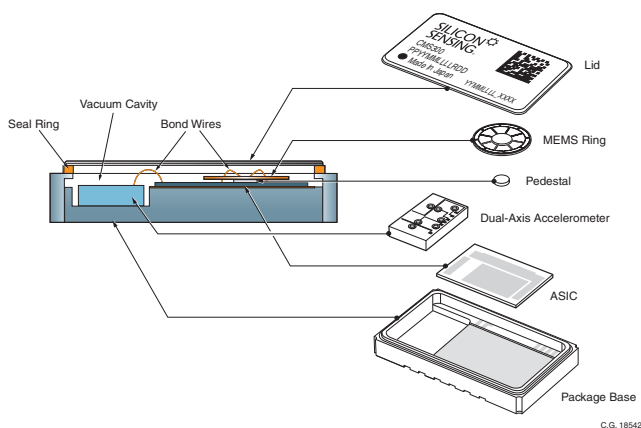


Figure 11.1 Combi-Sensor Main Components



Figure 11.2 Combi-Sensor (Lid Removed)

Silicon MEMS Ring Sensor (Gyro)

The 3mm diameter by 65µm thick silicon MEMS ring is fabricated by Silicon Sensing using a DRIE (Deep Reactive Ion Etch) bulk silicon process. The annular ring is supported in free-space by eight pairs of 'dog-leg' shaped symmetrical spokes which radiate from a central 1mm diameter solid hub.

The bulk silicon etch process and unique patented ring design enable close tolerance geometrical properties for precise balance and thermal stability and, unlike other MEMS gyros, there are no small gaps to create problems of interference and stiction. These features contribute significantly to DMU10's bias and scale factor stability over temperature, and vibration and shock immunity. Another advantage of the design is its inherent immunity to acceleration induced rate error, or 'g-sensitivity'.

Piezoelectric (strain) thin film actuators/transducers are attached to the upper surface of the silicon ring perimeter and are electrically connected to bond pads on the ring hub via tracks on the spokes. These actuate or 'drive' the ring into its Cos2θ mode of vibration at a frequency of 22kHz or detect radial motion of the ring perimeter either caused by the primary drive actuator or by the coriolis force effect when the gyro is rotating about its sensing axis. There is a single pair of primary drive actuators and a single pair of primary pick-off transducers, and two pairs of secondary pick-off transducers.

The combination of transducer technology and eight secondary pick-off transducers improves the DMU10's signal-to-noise ratio, the benefit of which is a very low-noise device with excellent bias over temperature performance.

Silicon MEMS Dual-Axis Accelerometer

The Combi-Sensor dual-axis open loop accelerometer is a one-piece resonating silicon MEMS structure anodically bonded to top and bottom glass substrates to form a hermetically sealed Silicon on Glass (SOG) wafer sub-assembly. The same DRIE bulk silicon process as used to create the gyro in is used to create two orthogonal finger-like spring/seismic proof mass structures, each measuring 1.8mm square, and with a resonant frequency of 2.9kHz. Figure 11.3 shows a schematic cross section through the SOG wafer.

Capacitive drive and pick-off signals are transmitted by wire bond interconnections, in through-glass vias, between the metallised transducer plates on the MEMS proof mass and the ASIC.

Multiple inter-digitated fingers create increased capacitance thus enabling a high signal-to-noise ratio. The fingers are tapered to increase the resonant frequency and also have a high aspect ratio to provide highly stable performance. The differential gaps between the static electrode fingers and those of the proof mass provide an air squeeze film with near-critical damping.

Control of the accelerometer is handled by the ASIC.

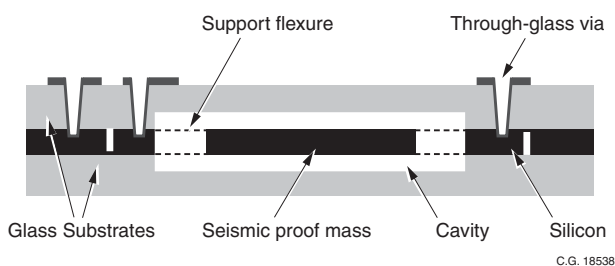


Figure 11.3 Schematic Section of the Silicon On Glass Accelerometer MEMS Wafer Sub-Assembly

Pedestal

The hub of the MEMS gyro ring is supported above the ASIC on a 1mm diameter cylindrical silicon pedestal, which is bonded to the ring and ASIC using an epoxy resin.

ASIC

The ASIC is a 5.52mm x 3.33mm device fabricated using 0.35µm CMOS process. ASIC and MEMS are physically separate and are connected electrically by using gold bond wires and thus the ASIC has no MEMS-to-ASIC internal tracking, meaning there is reduced noise pick-up and excellent EMC performance. Gold bond wires also connect the ASIC to the internal bond pads on the Package Base.

Package Base and Lid

The LCC ceramic Package Base is a multi-layer aluminium oxide construction with internal bond wire pads connected through the Package Base via integral multi-level tungsten interconnects to a series of external solder pads. Similar integral interconnects in the ceramic layers connect the Lid to Vss, thus the sensitive elements are inside a Faraday shield for excellent EMC. Internal and external pads are electroplated gold on electroplated nickel.

The Package Base incorporates a seal ring on the upper layer onto which a Kovar® metal Lid is seam welded using a rolling resistance electrode, thus creating a totally hermetic seal. Unlike other MEMS Inertial Sensor packages available on the market, the DMU10 Combi Sensor has a specially developed seam weld process which eliminates the potential for internal weld spatter. Inferior designs can cause dislodged weld spatter which affects gyro reliability due to interference with the vibratory MEMS element, especially where the MEMS structure has small gaps, unlike Combi-Sensor with its large gaps as described above.

Theory of Operation (Gyro)

The rate sensor is a solid-state device and thus has no moving parts other than the deflection of the ring itself. It detects the magnitude and direction of angular velocity by using the 'coriolis force' effect. As the gyro is rotated coriolis forces acting on the silicon ring cause radial movement at the ring perimeter.

There are eight actuators/transducers distributed evenly around the perimeter of the silicon MEMS ring. Located about its primary axes (0° and 90°) are a single pair of 'primary drive' actuators and a single pair of 'primary pick-off' transducers. Located about its secondary axes (45° and 135°) are two pairs of 'secondary pick-off' transducers.

The 'primary drive' actuators and 'primary pick-off' transducers act together in a closed-loop system to excite and control the ring primary operating vibration amplitude and frequency (22kHz). Secondary 'pick-off' transducers detect radial movement at the secondary axes, the magnitude of which is proportional to the angular speed of rotation and from which the gyro derives angular rate.

The transducers produce a double sideband, suppressed carrier signal, which is demodulated back to a baseband. This gives the user complete flexibility over in system performance, and makes the transduction completely independent of DC or low frequency parametric conditions of the electronics.

Referring to Figures 11.4(a) to 11.4(d)

Figure 11.4(a) shows the structure of the silicon MEMS ring. Figure 11.4(b) shows the ring diagrammatically, the spokes, actuators and transducers removed for clarity, indicating the Primary Drive actuators (single pair), Primary Pick-Off transducers (single pair) and Secondary Pick-Off transducers (two pairs).

In Figure 11.4(b) the annular ring is circular and is representative of the gyro when unpowered.

When powered-up the ring is excited along its primary axes using the Primary Drive actuators and Primary Pick-Off transducers acting in a closed-loop control system within the ASIC. The circular ring is deformed into a 'Cos2 θ ' mode which is elliptical in form and has a natural frequency of 22kHz. This is depicted in Figure 11.4(c). In Figure 11.4(c) the gyro is powered-up but still not rotating. At the four Secondary Pick-Off nodes located at 45° to the primary axes on the ring perimeter there is effectively no radial motion.

If the gyro is now subjected to applied angular rate, as indicated in Figure 11.4(d), then this causes the ring to be subjected to coriolis forces acting at a tangent to the ring perimeter on the primary axes. These forces in turn deform the ring causing radial motion at the Secondary Pick-Off transducers. It is the motion detected at the Secondary Pick-off transducers which is proportional to the applied angular rate. The signal is demodulated with respect to the primary motion, which results in a low frequency component which is proportional to angular rate. All of the gyro control circuitry is hosted in the ASIC. A block diagram of the ASIC functions is given in Figure 1.1 in Section 1.

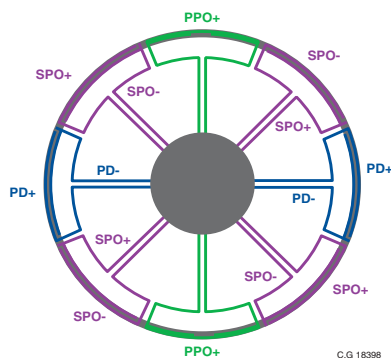


Figure 11.4(a)

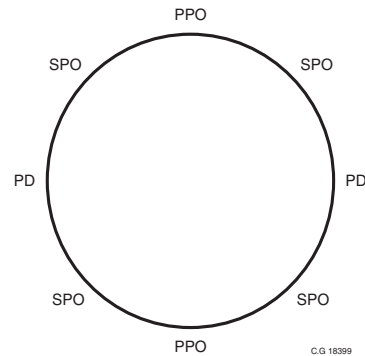


Figure 11.4(b)

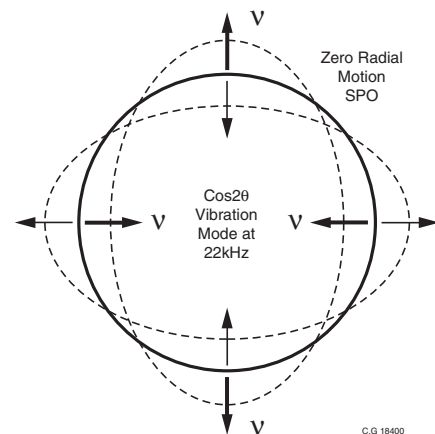


Figure 11.4(c)

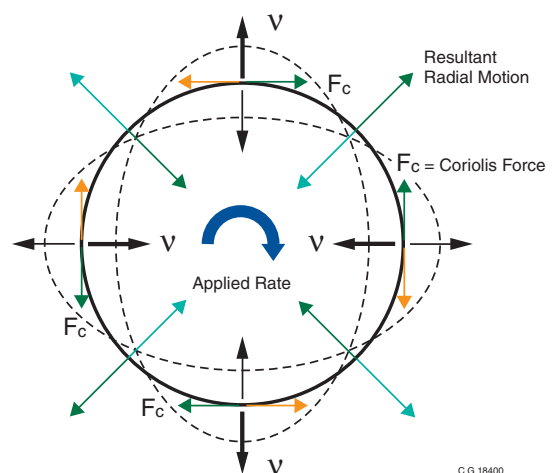


Figure 11.4(d)

Theory of Operation (Accelerometer)

The accelerometer contains a seismic 'proof mass' with multiple fingers suspended via a 'spring', from a fixed supporting structure. The supporting structure is anodically bonded to the top and bottom glass substrates and thereby fixed to the sensor package base.

When the accelerometer is subjected to a linear acceleration along its sensitive axis, the proof mass tends to resist motion due to its own inertia, therefore the mass and its fingers becomes displaced with respect to the interdigitated fixed electrode fingers (which are also fixed to glass substrates). Air between the fingers provides a damping effect. This displacement induces a differential capacitance between the moving and fixed silicon fingers which is proportional to the applied acceleration.

Capacitor plate groups are electrically connected in pairs at the top and bottom of the proof mass. In-phase and anti-phase waveforms are applied by the ASIC separately to the 'left' and 'right' finger groups. The demodulated waveforms provide a signal output proportional to linear acceleration.

Figures 11.5(a) and 11.5(b) provide schematics of the accelerometer structure and control loop respectively.

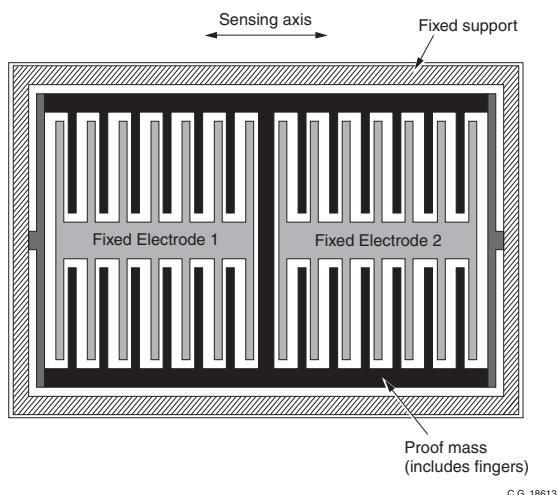


Figure 11.5(a) Schematic of Accelerometer Structure

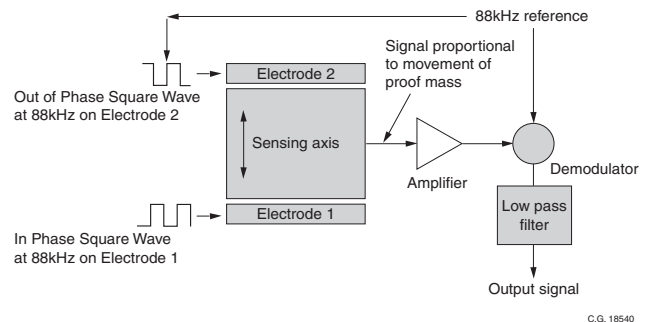


Figure 11.5(b) Schematic of Accelerometer Control Loop

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Notes

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